Tezen, Yuta

Aichi

JΡ

Hiramatsu, Toshio

Aichi

JР

US-CL-CURRENT: 117/103; 117/84, 257/E21.127, 257/E21.131

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KIMIC	Draws De

3. Document ID: US 20040016396 A1

L7: Entry 3 of 34

File: PGPB

Jan 29, 2004

RULE-47



PGPUB-DOCUMENT-NUMBER: 20040016396

PGPUB-FILING-TYPE: new

DOCUMENT-IDENTIFIER: US 20040016396 A1

1010,10,139,6

TITLE: Method for producing semiconductor crystal

PUBLICATION-DATE: January 29, 2004

INVENTOR-INFORMATION:

NAME CITY

CITY STATE COUNTRY Nishikasugai-gun JP

Nagai, Seiji Kojima, Akira

Nishikasuqai-gun

JP

Tomita, Kazuyoshi

Nagoya-shi

JP

US-CL-CURRENT: (1

x <u>257/E21.113</u>, <u>257/E21.127</u>, <u>257/E21.131</u>

****	Full	Title	Citation	Frent	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KMIC	Отам Ос
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4. Document ID: US 20030134446 A1

L7: Entry 4 of 34

File: PGPB

Jul 17, 2003

PGPUB-DOCUMENT-NUMBER: 200\30134446

PGPUB-FILING-TYPE: new

DOCUMENT-IDENTIFIER: US 20030\(\)34446 A1

TITLE: Production method of III hitride compound semiconductor and III nitride

compound semiconductor element

PUBLICATION-DATE: July 17, 2003

INVENTOR-INFORMATION:

NAME CITY

Koike, Masayoshi Nishikasugai-gun

Tezen, Yuta Nishikasugai-gun Yamashita, Hiroshi Nishikasugai-gun

Nagai, Seiji Nishikasugai-gun

Hiramatsu, Toshio Nishikasugai-gun

STATE COUNTRY RULE-47

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Record List Display Page 3 of 6

US-CL-CURRENT: 438/41; 257/E21.131

Full Title Citation Front Review Classification Date Reference Sequences Attachments Claims KNNC Draw De 5. Document ID: US 20030124789 A1 L7: Entry 5 of 34 File: PGPB Jul 3, 2003 PGPUB-DOCUMENT-NUMBER: 20030124789 PGPUB-FILING-TYPE: new DOCUMENT-IDENTIFIER: US 20030124789 A1 TITLE: Semiconductor light-emitting device and manufacturing method thereof PUBLICATION-DATE: July 3, 2003 INVENTOR-INFORMATION: CITY STATE COUNTRY RULE-47 NAME Koide, Norikatsu Aidhi JP Asami, Shinya Aichi JP Aich\i Umezaki, Junichi JP Koike, Masayoshi Aichì JΡ Yamasaki, Shiro Aichi JΡ <u>Nagai,</u> Seiji Aichi JΡ

US-CL-CURRENT: 438/200; 257/E29.078, 251/E33.008, 257/E33.028

Full Title Citation Front	Review Classification	Date Reference	Sequences Attac	hments Claims	KMMC - Draim De
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## 6. Document ID: US 20030010281 A1

L7: Entry 6 of 34

File: PGPB Jan 16, 2003

COUNTRY

RULE-47

PGPUB-DOCUMENT-NUMBER: 20030010281

PGPUB-FILING-TYPE: new

DOCUMENT-IDENTIFIER: US 20030010281 A1

TITLE: Semiconductor substrate

PUBLICATION-DATE: January 16, 2003

INVENTOR-INFORMATION:

NAME CITY

Koike, Masayoshi Nishikasugai-gun

JΡ Nagai, Seiji Nishikasugai-qun JΡ

US-CL-CURRENT: 117/97

Full Title Citation Front Review Classification Date Reference Sequences Attachments Claims

STATE

h e b b g ee e f b ef 7. Document ID: US 20020179005 A1

L7: Entry 7 of 34

File: PGPB

Dec 5, 2002

PGPUB-DOCUMENT-NUMBER: 20020179005

PGPUB-FILING-TYPE: new

DOCUMENT-IDENTIFIER: US 20020179005 A1

10 179,008

TITLE: Method for manufacturing group III nitride compound semiconductor and a light-emitting device using group III nitride compound semiconductor

PUBLICATION-DATE: December 5, 2002

INVENTOR-INFORMATION:

NAME CITY STATE COUNTRY RULE-47

Koike, Masayoshi Aichi-ken JP Nagai, Seiji Aichi-ken JP

US-CL-CURRENT: <u>117/84</u>; <u>257/E21.113</u>, <u>257/E21.125</u>

Full Title Citation Front Review Classification Date Reference Sequences Attachments Claims KMC Draw Do

8. Document ID: US 20020146854 A1

L7: Entry 8 of 34 File: PGPB

Oct 10, 2002

PGPUB-DOCUMENT-NUMBER: 20020146854

PGPUB-FILING-TYPE: new

DOCUMENT-IDENTIFIER: US 20020146854 A1

TITLE: Semiconductor light-emitting device and manufacturing method thereof

PUBLICATION-DATE: October 10, 2002

INVENTOR-INFORMATION:

NAME	· dity	STATE	COUNTRY	RULE-47
Koide, Norikatsu	Aichi		JP	
Asami, Shinya	Aichi		JP	
Umezaki, Junichi	Aichi .		JP	
Koike, Masayoshi	Aidhi		JP	
Yamasaki, Shiro	Aichi		JP	
<u>Nagai,</u> Seiji	Aichi		JP	

US-CL-CURRENT: 438/22; 257/E29.078, 257/E33.008, 257/E33.028

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	1000C Draw	a De
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9. Document ID: US 20020006726 A1

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L7: Entry 9 of 34

File: PGPB

Jan 17, 2002

Dec 6, 2001

PGPUB-DOCUMENT-NUMBER: 20020006726

PGPUB-FILING-TYPE: new

DOCUMENT-IDENTIFIER: US 20020006726 A1

TITLE: METHOD FOR MANUFACTURING GROUP III NITRIDE COMPOUND SEMICONDUCTOR LASER

DIODES

PUBLICATION-DATE: January 17, 2002

INVENTOR-INFORMATION:

NAME	CITY	STATE	COUNTRY	RULE-47
YAMASAKI, SHIRO	INAZAWA-SHI		JP	
NAGAI, SEIJI	NAGOYA-SHI		JP	
KOIKE, MASAYOSHI	ichinomiya-shi		JP	
AKASAKI, ISAMU	NAGOYA-SHI		JP	
AMANO, HIROSHI	NAGOYA-SHI		JP	
YAMADA, ISAO	HIMEJI-SHI		JP	
MASUO, JIRO	KYOTO-SHI	•	JP	
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US-CL-CURRENT: 438/689

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10	Document ID: US 2001	0048112 A1			

File: PGPB

Full Title Citation Front Review Classification Date Reference Securences Attachments Claims KWC Draw Do

PGPUB-DOCUMENT-NUMBER: 20010048112

PGPUB-FILING-TYPE: new

L7: Entry 10 of 34

DOCUMENT-IDENTIFIER: US 20010048112 A1

TITLE: Semiconductor light-emitting device and manufacturing method thereof

PUBLICATION-DATE: December 6, 2001

INVENTOR-INFORMATION:

NAME	CITY	STATE	COUNTRY	RULE-47
Koide, Norikatsu	Aichi		JP	
Asami, Shinya	Aichi		JP	
Umezaki, Junichi	Aich <b></b>	•	JP	
Koike, Masayoshi	Aichi		JP	
Yamasaki, Shiro	Aichi\		JP ·	
<u>Nagai,</u> Seiji	Aichi \		JP	

US-CL-CURRENT: <u>257/94</u>; <u>257/104</u>, <u>257/E29.078</u>, <u>257/E33.008</u>, <u>257/E33.028</u>

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KMMC	Draint De
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Search Results - Record(s) 1 through 10 of 34 returned.

1. Document ID: US 20040219702 A1

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L7: Entry 1 of 34

File: PGPB

10/210,762

Nov 4, 2004

PGPUB-DOCUMENT-NUMBER: 20040219702

PGPUB-FILING-TYPE: new

DOCUMENT-IDENTIFIER: US 20040219702 A1

TITLE: Method for manufacturing group-III nitride compound semiconductor, and

group-III nitride compound semiconductor device

PUBLICATION-DATE: November 4, 2004

INVENTOR-INFORMATION:

h

NAME CITY STATE COUNTRY RULE-47
Nagai, Seiji Aichi JP

Koike, Masayoshi Aichi JP Tomita, Kazuyoshi Aichi JP

US-CL-CURRENT: 438/46; 438/47, 438/478, 438/481

b g ee e f

Full   Title   Citation   Front   Review   C	inan Kiran ilan Interi		Casuancas Stach	nenta   Claims   KWMC   Draw De
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PGPUB-DOCUMENT-NUMBER: 20040123	3796		///0	
PGPUB-FILING-TYPE: new DOCUMENT-IDENTIFIER: US 200\( \)012	23796 A1	$\wedge$		
	,	1/1	$\mathbb{R}/\mathbb{N}$	
TITLE: Production method for	miconducto	rcrystal	and semicondu	actor luminous
element	\	$\parallel \parallel \parallel \sim$		
PUBLICATION-DATE: July 1, 2004		4 1		
INVENTOR-INFORMATION:				45
NAME	CITY	STATE	COUNTRY	RULE-47
<u>Nagai,</u> Seiji	Aichi 🔪		JP	
Tomita, Kazuyoshi	Aichi		JP	
Yamazaki, Shiro	Aichi		JP	•

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b